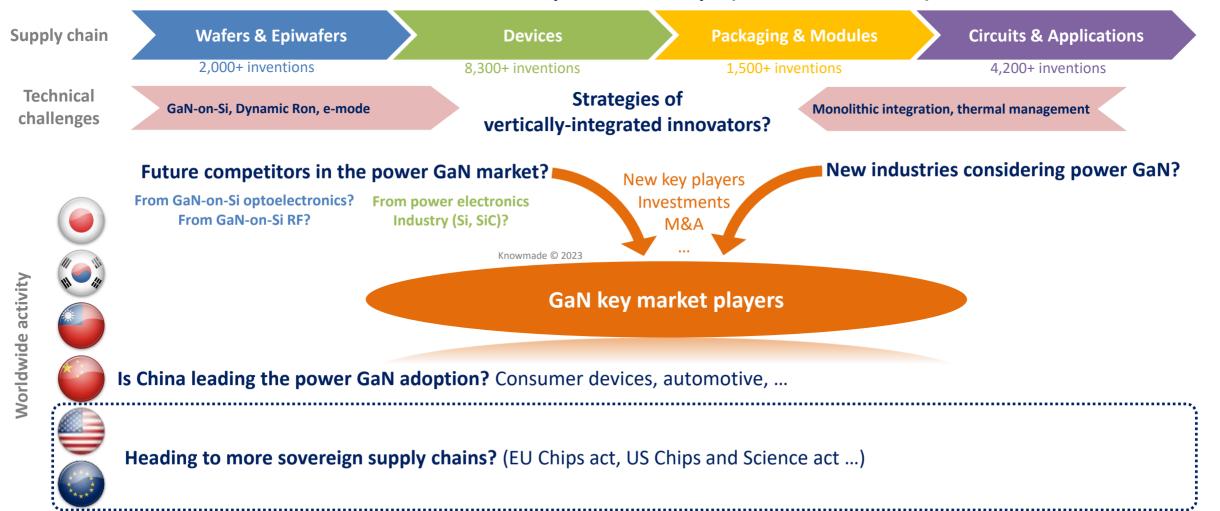
# From Technologies to IP Business Intelligence POWER GaN Patent Landscape Analysis April 2023 PE International Rémi COMYN remi.comyn@knowmade.fr © 2023 | www.knowmade.com

#### POWER GAN PATENT LANDSCAPE

Patent investigation of the power GaN ecosystem

Use the patent information to anticipate and understand new competitions in the GaN industry (business, technology and IP)

#### **Power GaN Electronics patent landscape (10,000+ inventions)**



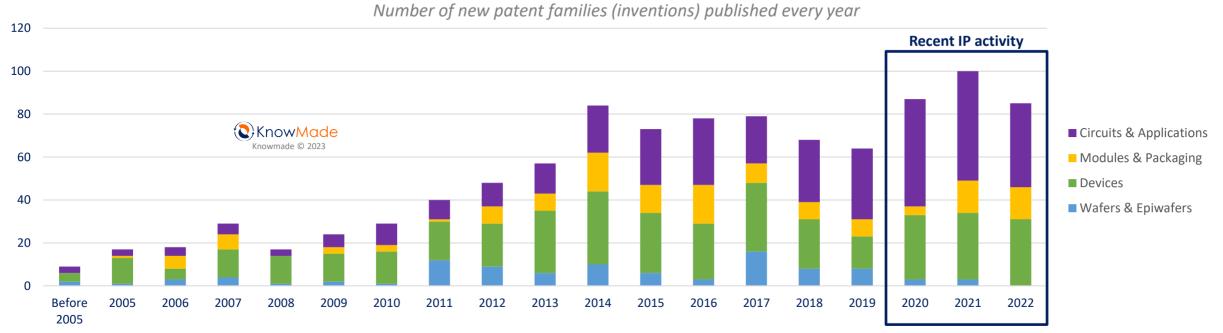


#### THE IP ACTIVITY OF EUROPEAN PLAYERS

Europe heading to a more sovereign supply chain?



#### IP activity of European IP players across the Power GaN supply chain



Overall, European players have been focusing their IP activities on the downstream supply chain

- European IP players have been focusing on Devices, Circuits & Applications
- The Circuits & Applications IP activity accelerated in 2019/2020
- The Wafers & Epiwafers IP activity is slowing down steadily
- The Modules & Packaging IP activity is strengthening



## A PATENT PERSPECTIVE ON EUROPEAN POWER GAN SUPPLY CHAIN

Europe heading to a more sovereign supply chain?



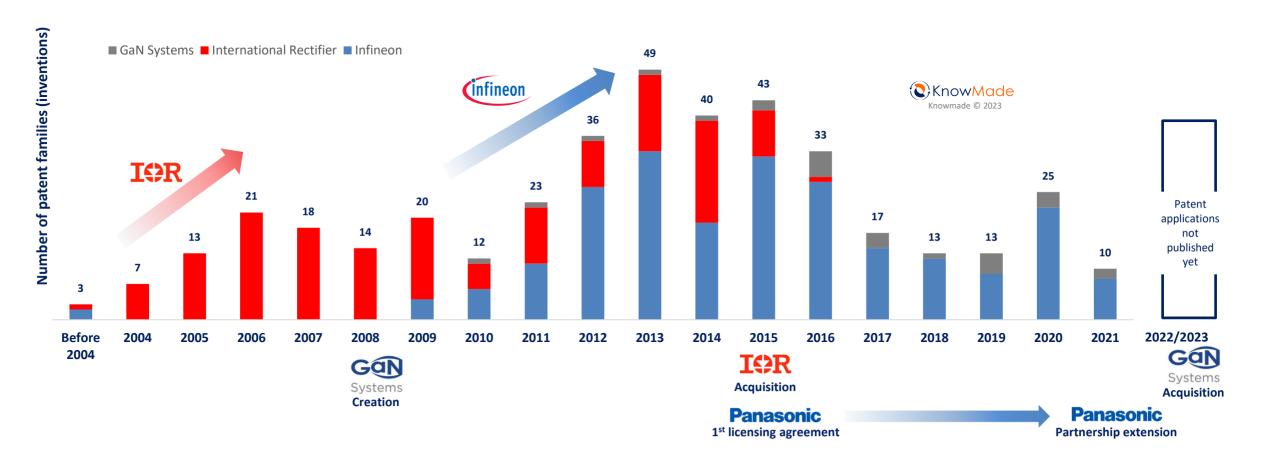


## INFINEON INVESTMENTS IN POWER GAN SUPPLY CHAIN



A patent look at the acquisitions and partnerships

#### Timeline of new patent applications filed by Infineon, International Rectifier & GaN Systems



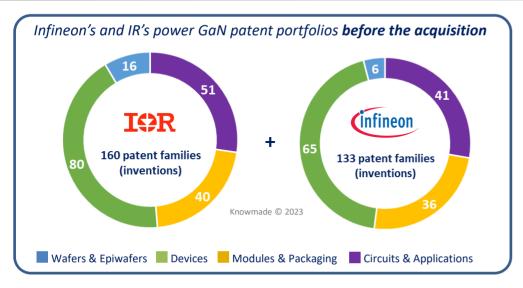
How does this strategy impact Infineon's patent portfolio?

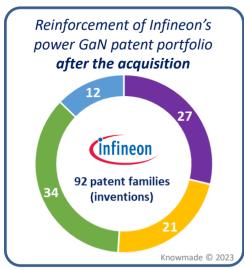


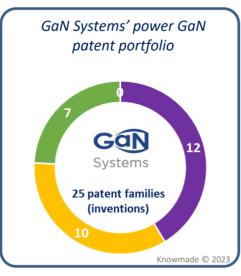
## INFINEON INVESTMENTS IN POWER GAN SUPPLY CHAIN

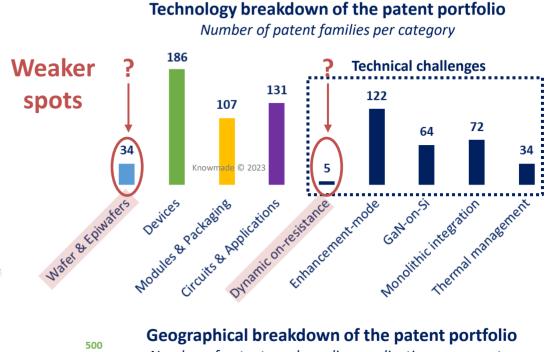


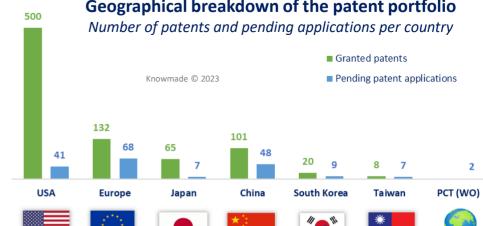
How does this strategy impact Infineon's IP position?











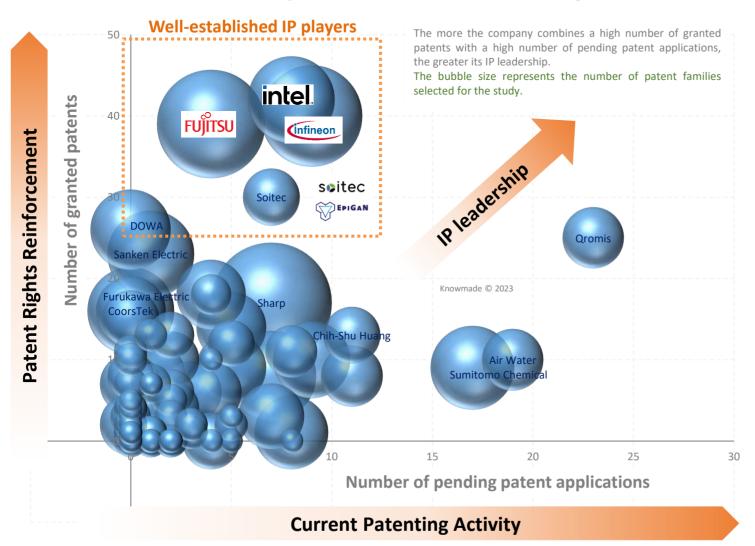


#### **GAN-ON-SI EPIWAFERS**

## Is the IP competition over?



#### GaN-on-Si epiwafers technical challenge



Infineon stands out as an IP leader for GaN-on-Si epiwafers (high number of granted patents)

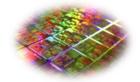
The IP competition related to GaN-on-Si is slowing down:

- Few stand-out well-established IP leaders
- No IP leader on conventional GaN-on-Si epiwafers
- Few IP challengers

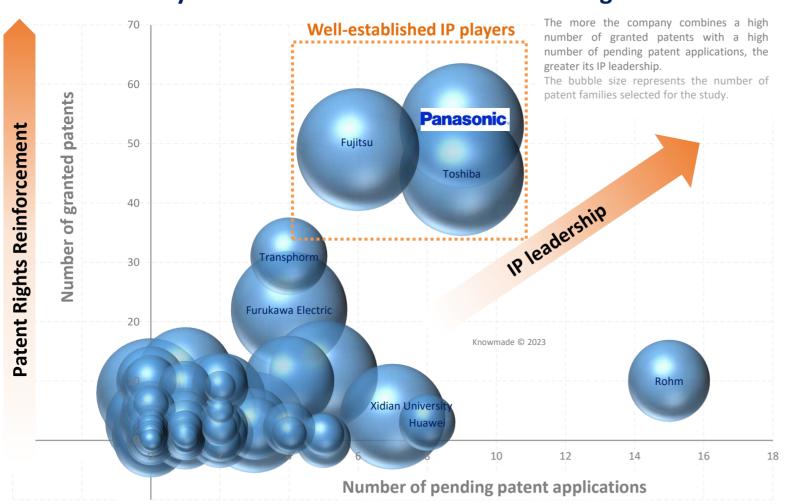


#### **DYNAMIC ON-RESISTANCE**

## Panasonic's leadership to benefit to Infineon's IP strategy?



#### **Dynamic on-resistance technical challenge**



Panasonic leads the IP activity related to dynamic on-resistance of Power GaN devices

From a patent perspective, the deal with

Panasonic also strengthens Infineon's IP

position related to dynamic Ron

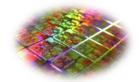
solutions

**Current Patenting Activity** 

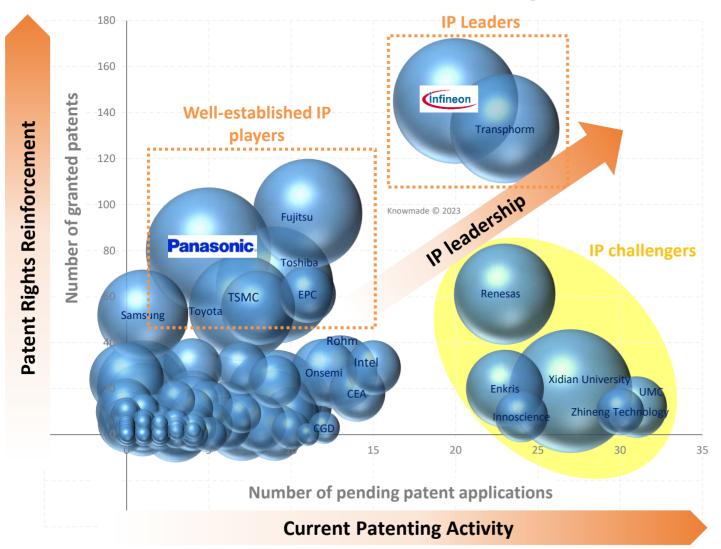


#### **E-MODE DEVICES**

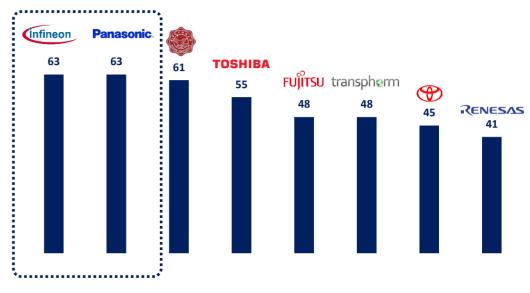
## Where is the current competition for Power GaN IP?



#### e-mode GaN technical challenge



## Main innovators for e-mode GaN devices Number of patent families



Infineon and Panasonic stand out as top
innovators for e-mode GaN devices
(number of inventions)

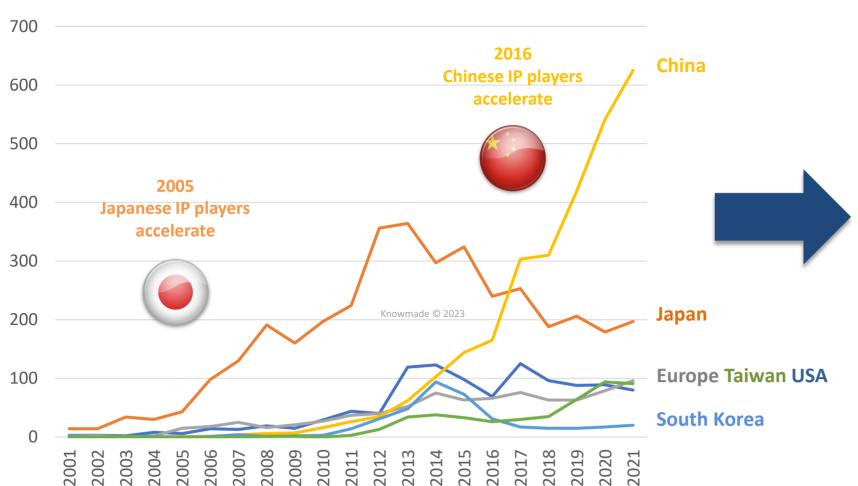


#### CHINA IN THE POWER GAN IP LANDSCAPE

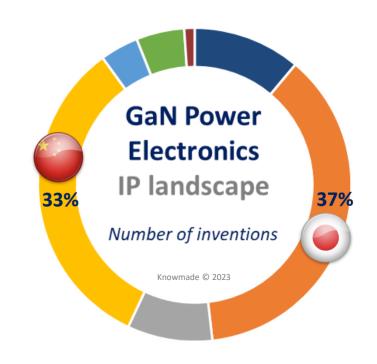
Is China leading the power GaN adoption?



## **GaN Power Electronics: Time evolution of the patenting activity by company headquarters**



Chinese IP players are catching up in terms of patenting activity



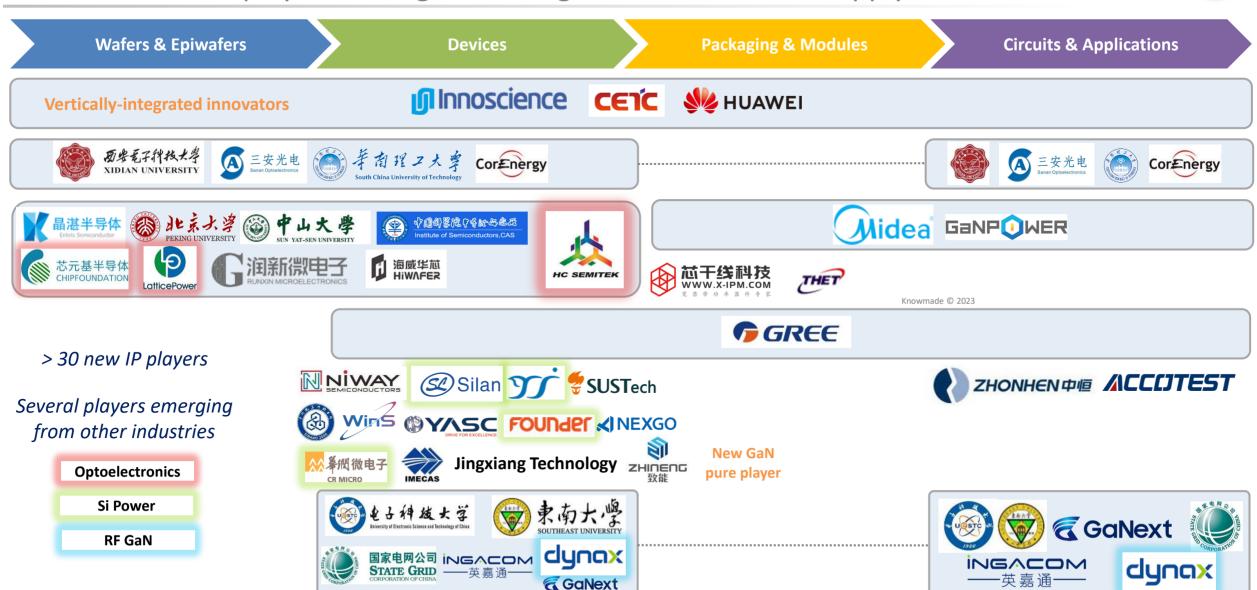
But how close is China to close the gap with the well-established countries?



#### A PATENT PERSPECTIVE ON THE POWER GAN SUPPLY CHAIN IN CHINA

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Who are the main players driving the emergence of a domestic supply chain?





## **CHINESE IP ACTIVITY OVERSEAS**

Chinese players with international ambitions







## **CHINESE VERTICALLY INTEGRATED INNOVATORS**



How does Innoscience's IP activities support its strategy in the Power GaN competition?

#### Wafers & Epiwafers

#### Devices

#### **Packaging & Modules**

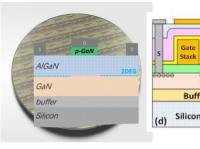
#### **Circuits & Applications**

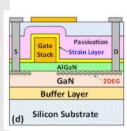
2023

Innoscience SolidGaN chip

#### 2015-2020

Innoscience R&D activities covering 8inch GaN-on-Si epitaxy and e-mode GaN HEMT processina





#### 2021-2023

Innoscience released and extended its InnoGaN series products (discrete devices)

#### 30V-150V - Low & Medium Voltage InnoGaN™



Single, 7mΩ max, 29A

Solder Bar CSP 2 5 x 1 5













Single 600m0 may 5.04



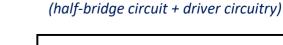
INN650DA500A Single, 500mΩ max, 7A DFN 5x6

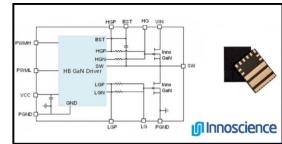
Single 140m0 may 174





Single 240mO may 124





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Single, 7mΩ max, 28A

FCLGA 2.2 x 3.2

## **Innoscience**

Innoscience published its first patent applications in 2017, focusing on wafers and epiwafers

Limited number of inventions related to **devices** until **2019** 

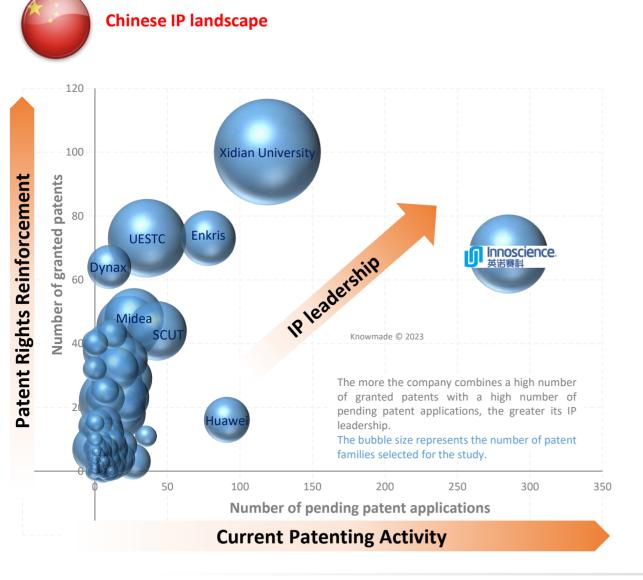
The IP activity related to devices took off in 2020 and accelerated in 2021/2022

Since 2020, Innoscience has been expanding its IP activities to the downstream supply chain



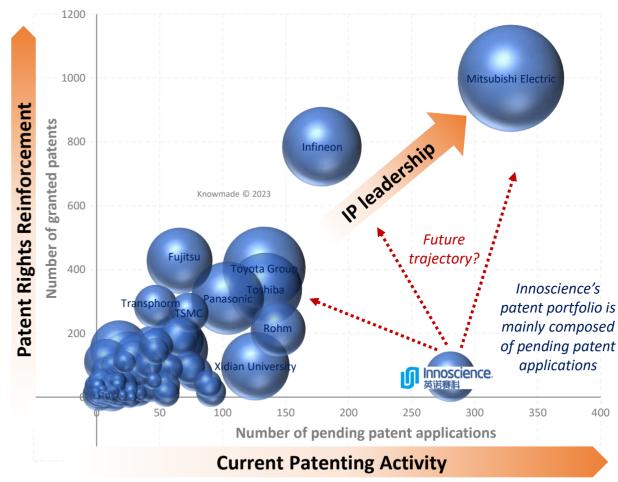
## **INNOSCIENCE IP LEADERSHIP**

A leading Chinese IP player and the main global IP challenger





#### **Global IP landscape**



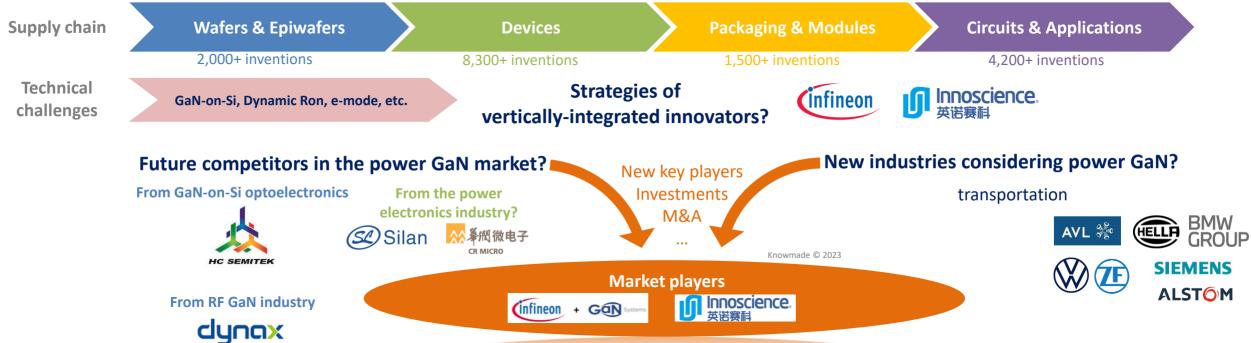


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Is China leading the power GaN adoption? Many Chinese IP players are emerging across the whole supply chain Innoscience is the main challenger with a vertically-integrated and global IP strategy



Heading to more sovereign supply chains?



















**Norldwide activity** 

#### **POWER GAN ECOSYSTEM**

## Take-away messages



**GaN Electronics for Power & RF applications** 



European IP landscape

#### **SUPPLY CHAIN ESTABLISHMENT**

- Significant IP activity from leading research organizations (CEA, imec, Fraunhofer)
- Industrial players took over the IP leadership across the whole supply chain (Infineon, ST, Bosch, Siemens)

#### **VERTICALLY-INTEGRATED INNOVATORS**

- **Infineon** confirmed its IP leadership after **IR**'s acquisition across the whole supply chain
- The partnership with Panasonic strengthens Infineon's IP position for e-mode GaN device and complete its patent portfolio for dynamic Ron
- GaN systems' patent portfolio will further enhance its position in the downstream supply chain

#### **IP** COMPETITION

- Infineon's and ST's patenting activity cover the largest markets for Power GaN technology (Asia, USA, Europe)
- The IP competition seems to be over for GaN-Si and slowing down for dynamic Ron
- Patent applicants currently focus on emode GaN devices including many Asian challengers and newcomers



Chinese IP landscape



- New players in the Power GaN IP landscape such as Ingacom, YASC, Niway Semiconductor, and Zhineng Technology
- Players coming from other industries such as HC Semitek, Dynax/Gpower, Silan, and CR Micro
- Innoscience, Huawei, CETC are the main Chinese vertically-integrated innovators
- Innoscience and Huawei have accelerated their patenting recently, expanding their activities across the supply chain in opposite directions
- Both players have been mainly assigned to pending patent applications so far (to be monitored)
- The main global IP competitors from China are Innoscience, Huawei and Enkris Semiconductor
- Innoscience and Enkris Semiconductor have focused their patenting activity on emode GaN devices so far





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